Low Skew, 1-to-16 DIFFERENTIAL-TO-3.3V LVPECL FANOUT BUFFER

GENERAL DESCRIPTION



The ICS8530-01 is a low skew, 1-to-16 Differential-to-3.3V LVPECL Fanout Buffer and a member of the HiPerClockS™family of High Performance Clock Solutions from ICS. The CLK, nCLK pair can accept most standard differential input

levels. The high gain differential amplifier accepts peak-to-peak input voltages as small as 150mV as long as the common mode voltage is within the specified minimum and maximum range.

Guaranteed output and part-to-part skew characteristics make the ICS8530-01 ideal for those clock distribution applications demanding well defined performance and repeatability.

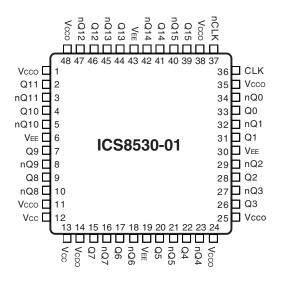
FEATURES

- 16 differential 3.3V LVPECL outputs
- CLK, nCLK input pair
- CLK, nCLK pair can accept the following differential input levels: LVDS, LVPECL, LVHSTL, SSTL, HCSL
- Maximum output frequency: 500MHz
- Translates any single-ended input signal to 3.3V LVPECL levels with a resistor bias on nCLK input
- Output skew: 75ps (maximum)
- Part-to-part skew: 250ps (maximum)
- Additive phase jitter, RMS: 0.03ps (typical)
- 3.3V output operating supply
- 0°C to 70°C ambient operating temperature
- Lead-Free package RoHS compliant
- · Industrial temperature information available upon request

BLOCK DIAGRAM

CLK nCLK Q15 nQ15 Q0 nQ0 Q1 nQ1 Q14 nQ14 Q2 nQ2 Q13 nQ13 Q3 Q12 nQ3 nQ12 Q4 Q11 nQ4 nΩ11 Q10 nQ5 nQ10 Q6 nQ6 nQ9 Q7 nQ7 Q8 nQ8

PIN ASSIGNMENT



48-Pin LQFP 7mm x 7mm x 1.4mm package body Y Package Top View

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TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	/ре	Description
1, 11, 14, 24, 25, 35, 38, 48	V _{cco}	Power		Output supply pins.
2, 3	Q11, nQ11	Output		Differential output pair. LVPECL interface levels.
4, 5	Q10, nQ10	Output		Differential output pair. LVPECL interface levels.
6, 19, 30, 43	$V_{_{EE}}$	Power		Negative supply pins.
7, 8	Q9, nQ9	Output		Differential output pair. LVPECL interface levels.
9, 10	Q8, nQ8	Output		Differential output pair. LVPECL interface levels.
12, 13	V_{cc}	Power		Core supply pins.
15, 16	Q7, nQ7	Output		Differential output pair. LVPECL interface levels.
17, 18	Q6, nQ6	Output		Differential output pair. LVPECL interface levels.
20, 21	Q5, nQ5	Output		Differential output pair. LVPECL interface levels
22, 23	Q4, nQ4	Output		Differential output pair. LVPECL interface levels.
26, 27	Q3, nQ3	Output		Differential output pair. LVPECL interface levels.
28, 29	Q2, nQ2	Output		Differential output pair. LVPECL interface levels.
36	CLK	Input	Pulldown	Non-inverting differential clock input.
37	nCLK	Input	Pullup	Inverting differential clock input.
39, 40	Q15, nQ15	Output		Differential output pair. LVPECL interface levels.
41, 42	Q14, nQ14	Output		Differential output pair. LVPECL interface levels.
44, 45	Q13, nQ13	Output		Differential output pair. LVPECL interface levels.
46, 47	Q12, nQ12	Output		Differential output pair. LVPECL interface levels.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ

TABLE 3. FUNCTION TABLE

Inp	outs	Outputs		Input to Output Made	Delevity
CLK	nCLK	Q0:Q15	nQ0:nQ15	Input to Output Mode	Polarity
0	1	LOW	HIGH	Differential to Differential	Non Inverting
1	0	HIGH	LOW	Differential to Differential	Non Inverting
0	Biased; NOTE 1	LOW	HIGH	Single Ended to Differential	Non Inverting
1	Biased; NOTE 1	HIGH	LOW	Single Ended to Differential	Non Inverting
Biased; NOTE 1	0	HIGH	LOW	Single Ended to Differential	Inverting
Biased; NOTE 1	1	LOW	HIGH	Single Ended to Differential	Inverting

NOTE 1: Please refer to the Application Information section, "Wiring the Differential Input to Accept Single Ended Levels".

Low Skew, 1-to-16 DIFFERENTIAL-TO-3.3V LVPECL FANOUT BUFFER

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{CC} 4.6V

Inputs, V_i -0.5V to V_{CC} + 0.5V

Outputs, I_O

Continuous Current 50mA Surge Current 100mA

Package Thermal Impedance, θ_{JA} 47.9°C/W (0 Ifpm)

Storage Temperature, $T_{\rm STG}$ -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 4A. Power Supply DC Characteristics, $V_{CC} = V_{CCO} = 3.3V \pm 5\%$, Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{cc}	Input/core Supply Voltage		3.135	3.3	3.465	V
V _{cco}	Output Supply Voltage		3.135	3.3	3.465	V
I _{EE}	Power Supply Current				140	mA

Table 4B. Differential DC Characteristics, $V_{cc} = V_{cco} = 3.3V \pm 5\%$, Ta = 0°C to 70°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
	Innut High Current	CLK	$V_{CC} = V_{IN} = 3.465V$			150	μΑ
IH	Input High Current	nCLK	$V_{CC} = V_{IN} = 3.465V$			5	μΑ
	Input Low Current	CLK	$V_{CC} = 3.465V, V_{IN} = 0V$	-5			μΑ
¹ _{IL}		nCLK	$V_{CC} = 3.465V, V_{IN} = 0V$	-150			μΑ
V _{PP}	Peak-to-Peak Input Voltage			0.15		1.3	V
V _{CMR}	Common Mode Input Voltage; NOTE 1, 2			V _{EE} + 0.5		V _{CC} - 0.85	V

NOTE 1: For single ended applications, the maximum input voltage for CLK, nCLK is V_{cc} + 0.3V.

NOTE 2: Common mode voltage is defined as V_{IH}.

Table 4C. LVPECL DC Characteristics, $V_{\rm CC} = V_{\rm CCO} = 3.3 V \pm 5\%$, Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{OH}	Output High Voltage; NOTE 1		V _{cco} - 1.4		V _{cco} - 1.0	V
V _{OL}	Output Low Voltage; NOTE 1		V _{cco} - 2.0		V _{cco} - 1.7	V
V _{SWING}	Peak-to-Peak Output Voltage Swing		0.6		0.85	V

NOTE 1: Outputs terminated with 50Ω to V_{cco} -2V.

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Table 5. AC Characteristics, $V_{CC} = V_{CCO} = 3.3V \pm 5\%$, Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				500	MHz
t _{PD}	Propagation Delay; NOTE 1	<i>f</i> ≤ 500MHz	1		2	ns
tsk(o)	Output Skew; NOTE 2, 4				75	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4			88	250	ps
<i>t</i> jit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	106.25MHz, Integration Range: 12KHz to 20MHz		0.03		ps
t _R	Output Rise Time	20% to 80% @ 50MHz	300		700	ps
t _F	Output Fall Time	20% to 80% @ 50MHz	300		700	ps
odc	Output Duty Cycle		47	50	53	%

All parameters measured at 250MHz unless noted otherwise.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

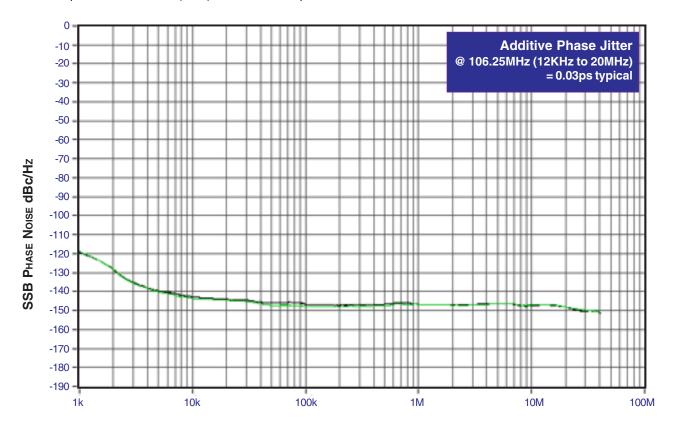
NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

ADDITIVE PHASE JITTER

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio of the power in

the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.



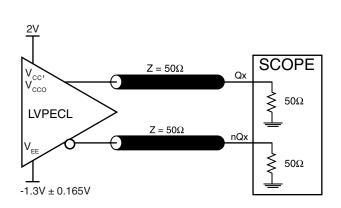
OFFSET FROM CARRIER FREQUENCY (Hz)

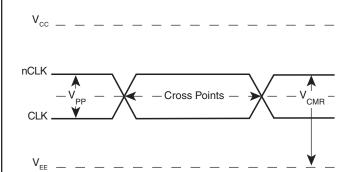
As with most timing specifications, phase noise measurements have issues. The primary issue relates to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This is illustrated above. The de-

vice meets the noise floor of what is shown, but can actually be lower. The phase noise is dependant on the input source and measurement equipment.

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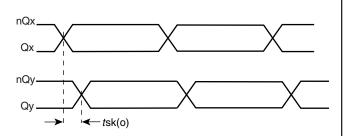
PARAMETER MEASUREMENT INFORMATION

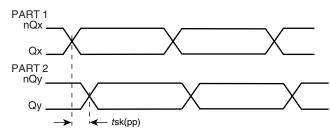




3.3V OUTPUT LOAD AC TEST CIRCUIT

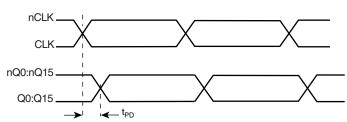


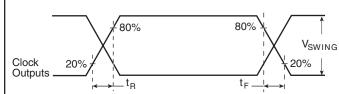




OUTPUT SKEW

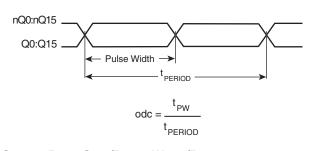
PART-TO-PART SKEW





PROPAGATION DELAY

OUTPUT RISE/FALL TIME



OUTPUT DUTY CYLE/PULSE WIDTH/PERIOD

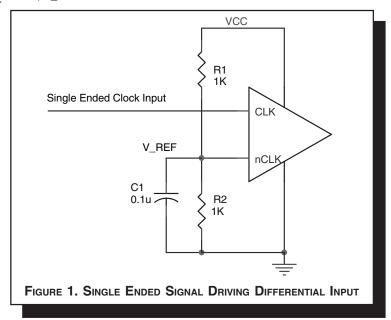


DIFFERENTIAL-TO-3.3V LVPECL FANOUT BUFFER

APPLICATION INFORMATION

WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LEVELS

Figure 1 shows how the differential input can be wired to accept single ended levels. The reference voltage V_REF $_{\sim}$ V $_{cc}$ /2 is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and V $_{cc}$ = 3.3V, V_REF should be 1.25V and R2/R1 = 0.609.



TERMINATION FOR LVPECL OUTPUTS

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

FOUT and nFOUT are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to

drive 50Ω transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 2A and 2B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

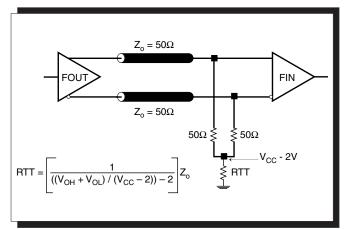


FIGURE 2A. LVPECL OUTPUT TERMINATION

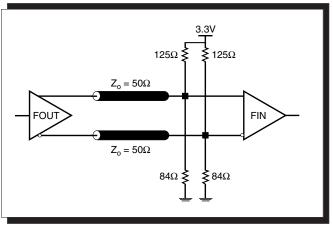


FIGURE 2B. LVPECL OUTPUT TERMINATION

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DIFFERENTIAL CLOCK INPUT INTERFACE

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. Figures 3A to 3E show interface examples for the HiPerClockS CLK/nCLK input driven by the most common driver types. The input interfaces suggested

here are examples only. Please consult with the vendor of the driver component to confirm the driver termination requirements. For example in *Figure 3A*, the input termination applies for ICS HiPerClockS LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

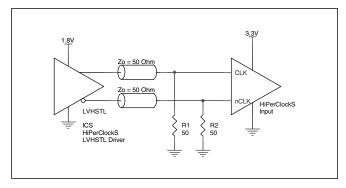


FIGURE 3A. HIPERCLOCKS CLK/nCLK INPUT DRIVEN BY ICS HIPERCLOCKS LVHSTL DRIVER

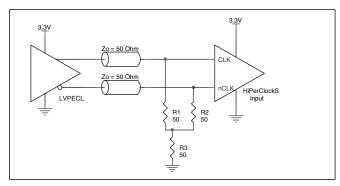


FIGURE 3B. HIPERCLOCKS CLK/nCLK INPUT DRIVEN BY 3.3V LVPECL DRIVER

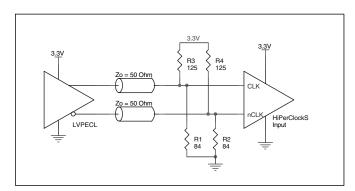


FIGURE 3C. HIPERCLOCKS CLK/nCLK INPUT DRIVEN BY 3.3V LVPECL DRIVER

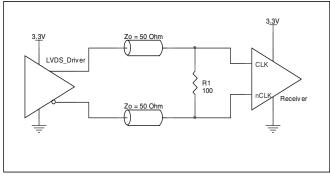


FIGURE 3D. HIPERCLOCKS CLK/nCLK INPUT DRIVEN BY 3.3V LVDS DRIVER

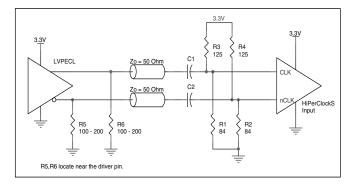


FIGURE 3E. HIPERCLOCKS CLK/NCLK INPUT DRIVEN BY 3.3V LVPECL DRIVER WITH AC COUPLE

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POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the ICS8530-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS8530-01 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = V_{CC MAX} * I_{EE MAX} = 3.465V * 140mA = 485.1mW
- Power (outputs)_{MAX} = 30.2mW/Loaded Output pair
 If all outputs are loaded, the total power is 16 * 30.2mW = 483.2mW

Total Power MAX (3.465V, with all outputs switching) = 485.1mW + 483.2mW = 968.3mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS TM devices is 125 $^{\circ}$ C.

The equation for Tj is as follows: Tj = θ_{IA} * Pd_total + T_A

Tj = Junction Temperature

 θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

 $T_A =$ Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance $\theta_{\rm JA}$ must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 47.9°C/W per Table 6 below.

Therefore, Tj for an ambient temperature of 70°C with all outputs switching is:

 $70^{\circ}\text{C} + 0.968\text{W} * 47.9^{\circ}\text{C/W} = 116.4^{\circ}\text{C}$. This is below the limit of 125°C .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

Table 6. Thermal Resistance θ_{JA} for 48-pin LQFP, Forced Convection

UA 5			
	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

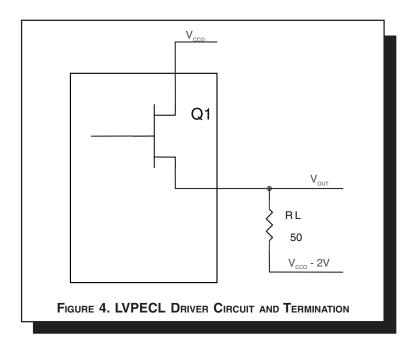
θ, by Velocity (Linear Feet per Minute)



3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in Figure 4.



To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of V $_{\text{CCO}}$ - 2V.

• For logic high,
$$V_{OUT} = V_{OH_MAX} = V_{CCO_MAX} - 1.0V$$

$$(V_{CCO_MAX} - V_{OH_MAX}) = 1.0V$$

• For logic low,
$$V_{OUT} = V_{OL_MAX} = V_{CCO_MAX} - 1.7V$$

$$(V_{CCO_MAX} - V_{OL_MAX}) = 1.7V$$

Pd_H is power dissipation when the output drives high. Pd_L is the power dissipation when the output drives low.

$$Pd_{-}H = [(V_{OH_MAX} - (V_{CCO_MAX} - 2V))/R_{L}] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - (V_{CCO_MAX} - V_{OH_MAX}))/R_{L}] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - 1V)/50\Omega] * 1V = 20.0mW$$

$$Pd_L = [(V_{OL_MAX} - (V_{CCO_MAX} - 2V))/R_{L}] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - (V_{CCO_MAX} - V_{OL_MAX}))/R_{L}] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = 10.2mW$$

Total Power Dissipation per output pair = Pd H + Pd L = 30.2mW

ICS8530-01 Low Skew, 1-to-16 DIFFERENTIAL-TO-3.3V LVPECL FANOUT BUFFER

RELIABILITY INFORMATION

Table 7. $\theta_{\text{JA}} \text{vs. Air Flow Table for 48 Lead LQFP}$

θ_{JA} by Velocity (Linear Feet per Minute)

	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for ICS8530-01 is: 930



PACKAGE OUTLINE - Y SUFFIX FOR 48 LEAD LQFP

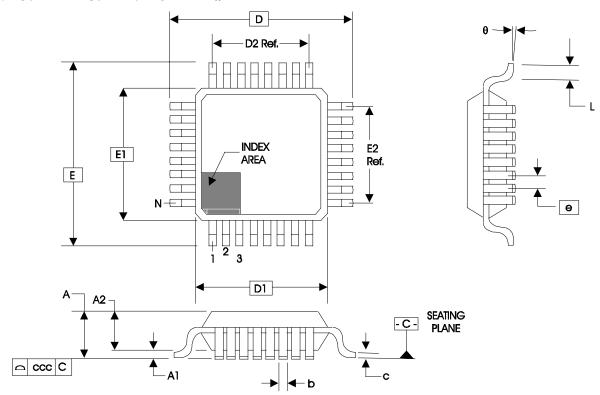


TABLE 8. PACKAGE DIMENSIONS

	JEDEC VARIATION ALL DIMENSIONS IN MILLIMETERS						
SYMBOL		BBC					
STWIBOL	MINIMUM	NOMINAL	MAXIMUM				
N		48					
Α			1.60				
A 1	0.05		0.15				
A2	1.35	1.40	1.45				
b	0.17	0.17 0.22 0.27					
С	0.09		0.20				
D		9.00 BASIC					
D1		7.00 BASIC					
D2		5.50 Ref.					
E		9.00 BASIC					
E1		7.00 BASIC					
E2		5.50 Ref.					
е		0.50 BASIC					
L	0.45	0.60	0.75				
θ	0°		7°				
ccc			0.08				

Reference Document: JEDEC Publication 95, MS-026



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TABLE 9. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
ICS8530DY-01	ICS8530DY-01	48 Lead LQFP	tray	0°C to 70°C
ICS8530DY-01T	ICS8530DY-01	48 Lead LQFP	1000 tape & reel	0°C to 70°C
ICS8530DY-01LF	ICS8530D01LF	48 Lead "Lead-Free" LQFP	tray	0°C to 70°C
ICS8530DY-01LFT	ICS8530D01LF	48 Lead "Lead-Free" LQFP	1000 tape & reel	0°C to 70°C

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Low Skew, 1-to-16 DIFFERENTIAL-TO-3.3V LVPECL FANOUT BUFFER

	REVISION HISTORY SHEET						
Rev	Rev Table Page Description of Change						
В		5-6 7	Updated figures. Added Termination for LVPECL Outputs section.	05/28/02			
Б		2	Pin Description table - V _{CC} description changed to "Core supply pin" from "Positive supply pin".	10/00/00			
В		5	Output Load Test Circuit diagram - corrected VEE equation to read, $V_{EE} = -1.3V \pm 0.165V$ from $V_{EE} = -1.3V \pm 0.135V$.	10/02/02			
	T2	2	Pin Characteristics table - changed C _{IN} 4pF max. to 4pF typical.				
		3	Updated AMR Output rating.				
	T4A	3	Power Supply table - changed I _{FE} max. from 120mA to 140mA.				
С		6	Updated Single Ended Signal Driving Differential Input diagram.	4/7/04			
		7	Added Differential Clock Input Interface section.	4/7/04			
		8	Power Considerations, changed $I_{\rm EE}$ to 140mA to reflect the Power Supply table and recalculated the equations.				
			Update format throughout the data sheet.				
С	Т9	12	Added "Lead-Free" marking to Ordering Information Table.	6/29/04			
		1	Features section - added Additive Phase Jitter bullet.				
D	T5	4	AC Characteristics table - added tjit row.	2/28/05			
		5	Added Additive Phase Jitter section.				